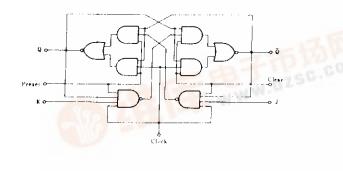
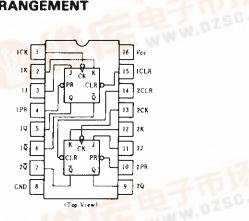


BLOCK DIAGRAM $(\frac{1}{2})$

PIN ARRANGEMENT





■RECOMMENDED OPERATING CONDITIONS

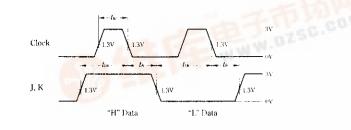
Item Clock frequency		Symbol	min	typ	max	Unit
		fetock	0		30	MHz
	Clock High		20	c.L	5 G	ns
Pulse width	Clear Preset Low	t.	25	_	·	
Setup time	"H"Data		201	-		1
	"L"Data	le u	20↓	~		ns ns
Hold time		th	10	_		מת

Note) 4: The arrow indicates the falling edge.

FUNCTION TABLE

	Out	puts				
Preset	Clear	Clock	J	к	Q	Q
L	Н	×	×	×	н	L
н	L	×	×	×	L	Н
L	L	×	×	×	H.	Н.
Н	Н	Ļ	L	L	Qu	Q ₀
Н	н		Н	L	н	L
н	Н	Ļ	L	н	L	н
н	н	Ļ	Н	н	Top	gle
Н	н	н	×	×	Qo	Qo

TIMING DEFINITION



s 98,

Notes) H; high level, L; low level, X; irrelevant

1; transition from high to low level

- Q₀; level of Q before the indicated steady-state input conditions were established.
- $\overline{Q}_{\mathfrak{o}}\,;\, \text{complement}$ of $Q_{\mathfrak{o}}\,$ or level of \overline{Q} before the indicated steady-state input conditions were established.
- Toggle; each output changes to the complement of its previous level on each active transition indicated by 4.
- *; This configuration is nonstable; that is, it will not persist when preset and clear inputs return to their inactive (high) level.

Item	1	Symbol	Test Conditions		min	typ*	max	Unit
		Vin			2.0	-		V
Input voltage		VIL			_	-	0.8	v
		Von	Vcc=4.75V, VIH=2V, VIL=0.8	V, Іон = - 400 µA	2.7	-		v
Output voltage		Vol	$V_{CC} = 4.75V, V_{IH} = 2V$	$I_{OL} = 8 m A$	-		0.5	- v
			$V_{lL}=0.8V$	$I_{OL} = 4 \text{mA}$		-	0.4	
	J, K		$V_{\rm CC} = 5.25 {\rm V}, V_{\rm I} = 2.7 {\rm V}$			-	20	μA
Clear Preset		1.			_		60	
		Іін				_	60	
Input current Clock J. K Clear Preset Clock J, K Clear	Clock	1			-		80	
	J. K				-	-0.4	mA	
		- ••				-		-0.8
	Preset	- IIL**	$V_{cc} = 5.25 \text{V}, V_l = 0.4 \text{V}$	V/=0.4V		-		-0.8
	Clock	-		_		-0.8		
	J, K				-		0.1	
	1.	1/ _ F 0F3/ 1/ _ 73/	-	-	0.3	mA		
	Preset	<i>I</i> 1	$V_{cc} = 5.25 \text{V}, V_l = 7 \text{V}$		-	-	0.3	шл
	Clock	1			-		0.4	
Short-circuit output current Id		los	Vcc = 5.25V		- 20	-	-100	mA
Supply current	pply current * * * Icc Vcc=5.25V			-	4	8	mА	
Input clamp voltage V_{IK} $V_{CC} = 4.75V$, $I_{IN} = -18 \text{mA}$		A	-	-	-1.5	V		

ELECTRICAL CHARACTERISTICS (Ta=-20~+75°C)

VCC = 5V, Ta = 25°C *

** I_{II} should not be measured when preset and clear inputs are low at same time. *** With all outputs open, *ICC* is measured with the Q and \overline{Q} outputs high in turn. At the time of measurement, the clock input is grounded.

ESWITCHING CHARACTERISTICS (Vcc=5V, $Ta=25^{\circ}C$)

Item	Symbol	Inputs	Outputs	Test Conditions	min	typ	max	Unit
Maximum clock frequency	fmax				30	45		MHz
Propagation delay time	tPLH	Clear	0.7	$C_L = 15 \mathrm{pF}, R_L = 2 \mathrm{k} \Omega$	-	11	20	ns
	t PHL	Preset Clock	Q, Q			15	30	ns

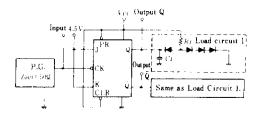


HD74LS112

TESTING METHOD

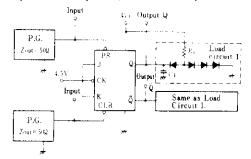
1) Test Circuit

1.1) f_{max} , t_{PLH} , t_{PHL} (Clock $\rightarrow 0, \overline{0}$)



- Notes) 1. Test is put into the each flip-flop.
 - 2. All diodes are 1\$2074 (D).
 - 3. C_L includes probe and jig capacitance.

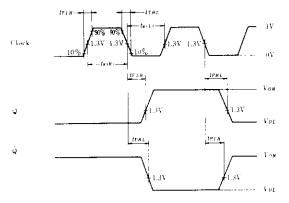
1.2) tPHL, tPLH (Clear, Preset-→Q,Q)



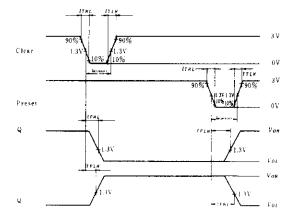
Notes) 1. Test is put into the each flip-flop. 2. All diodes are 1S2074 (P).

3. C_L includes probe and jig capacitance.



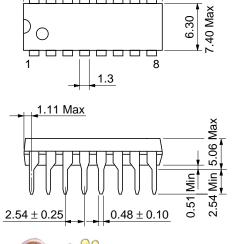


Note) Clock input pulse; $t_{TLH} \le 15$ ns, $t_{THL} \le 6$ ns, PRR = 1 MHz, duty cycle=50% and: for f_{max} , $t_{TLH} = t_{THL} \le 2.5$ ns.



Note) Clear and preset input pulse; $t_{TLH} \leq 15$ ns, $t_{THL} \leq 6$ ns, *PRR*=1MHz





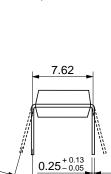
9

19.20 20.00 Max

Г

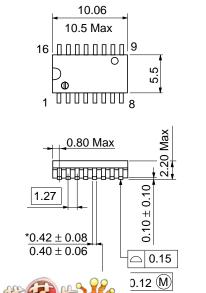
16

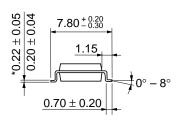




0° – 15°

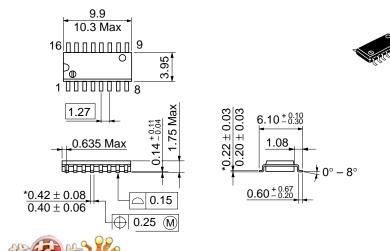
Unit: mm







Unit: mm



Unit: mm

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